

PART NUMBER 54ACTQ32Q2A-ROCA

Rochester Electronics Manufactured Components

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

 Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



OBSOLETE

January 2005

54ACTQ32

Quiet Series Quad 2-Input OR Gate

General Description

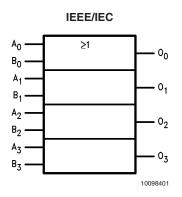
The 'ACTQ32 contains four, 2-input OR gates and utilizes NSC Quiet Series technology to guarantee quiet output switching and improved dynamic threshold performance. FACT Quiet Series™ features GTO™ output control and undershoot corrector in addition to a split ground bus for superior ACMOS performance.

- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Outputs source/sink 24 mA
- 'ACTQ32 has TTL-compatible inputs
- Standard Microcircuit Drawing (SMD) 5962-8973601

Features

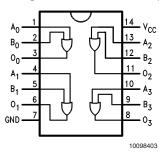
■ I_{CC} reduced by 50%

Logic Symbol

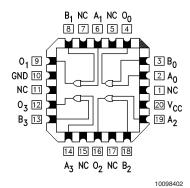


Connection Diagrams

Pin Assignment for DIP and Flatpak



Pin Assignment for LCC



Pin Names	Description		
A _n , B _n	Inputs		
O _n	Outputs		

GTO™ is a trademark of National Semiconductor Corporation.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

-0.5V to +7.0VSupply Voltage (V_{CC}) DC Input Diode Current (IIK) $V_1 = -0.5V$ -20 mA $V_I = V_{CC} + 0.5V$ +20 mA DC Input Voltage (V_I) -0.5V to $V_{\rm CC}$ + 0.5V DC Output Diode Current (IOK) $V_{O} = -0.5V$ -20 mA $V_O = V_{CC} + 0.5V$ +20 mA DC Output Voltage (V_O) -0.5V to $V_{\rm CC}$ + 0.5V

DC Output Source

or Sink Current (I_O) ± 50 mA

DC $\ensuremath{\text{V}_{\text{CC}}}$ or Ground Current

per Output Pin (I_{CC} or I_{GND}) ± 50 mA Storage Temperature (T_{STG}) -65° C to $+150^{\circ}$ C Junction Temperature (T_J)
CDIP

Recommended Operating Conditions

Supply Voltage (V_{CC})

 $\begin{tabular}{lll} 'ACTQ & 4.5V to 5.5V \\ Input Voltage (V_I) & 0V to V_{CC} \\ Output Voltage (V_O) & 0V to V_{CC} \\ \end{tabular}$

175°C

Operating Temperature (T_A)

54ACTQ -55°C to +125°C

Minimum Input Edge Rate $(\Delta V/\Delta t)$

'ACTQ Devices
V_{IN} from 0.8V to 2.0V

V_{CC} @ 4.5V, 5.5V 125 mV/ns

Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, without exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. National does not recommend operation of FACT™ circuits outside databook specifications.

DC Characteristics for 'ACTQ Family Devices

			54ACTQ			
Symbol	Parameter	V _{CC} T _A =		Units	Conditions	
		(V)				
			Guaranteed Limits			
V _{IH}	Minimum High Level	4.5	2.0	V	V _{OUT} = 0.1V	
	Input Voltage	5.5	2.0		or V _{CC} – 0.1V	
V _{IL}	Maximum Low Level	4.5	0.8	V	V _{OUT} = 0.1V	
	Input Voltage	5.5	0.8		or V _{CC} – 0.1V	
V _{OH}	Minimum High Level	4.5	4.4	V	I _{OUT} = -50 μA	
	Output Voltage	5.5	5.4			
					(Note 2)	
					$V_{IN} = V_{IL} \text{or } V_{IH}$	
		4.5	3.70	V	$I_{OH} = -24 \text{ mA}$	
		5.5	4.70		$I_{OH} = -24 \text{ mA}$	
V _{OL}	Maximum Low Level	4.5	0.1	V	I _{OUT} = 50 μA	
	Output Voltage	5.5	0.1			
					(Note 2)	
					$V_{IN} = V_{IL} \text{or } V_{IH}$	
		4.5	0.50	V	I _{OL} = 24 mA	
		5.5	0.50		I _{OL} = 24 mA	
I _{IN}	Maximum Input	5.5	±1.0	μA	$V_{I} = V_{CC}$, GND	
	Leakage Current					
I _{CCT}	Maximum	5.5	1.6	mA	$V_{I} = V_{CC} - 2.1V$	
	I _{CC} /Input					
I _{OLD}	Minimum Dynamic	5.5	50	mA	V _{OLD} = 1.65V Max	
I _{OHD}	Output Current (Note 3)	5.5	-50	mA	V _{OHD} = 3.85V Min	
I _{cc}	Maximum Quiescent	5.5	80.0	μA	$V_{IN} = V_{CC}$	
	Supply Current				or GND (Note 3)	

Note 2: All outputs loaded; thresholds on input associated with output under test.

Note 3: Maximum test duration 2.0 ms, one output loaded at a time.

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AC Electrical Characteristics

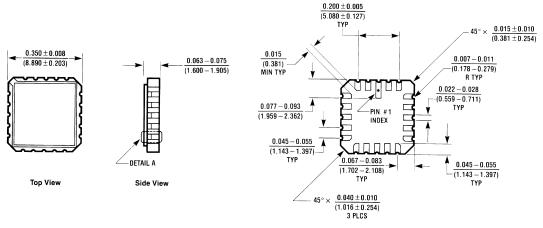
			54A0	CTQ		
Symbol	Parameter	V _{CC} (V) (Note 4)	T _A = -55°C to +125°C C _L = 50 pF		Units	Fig. No.
			Min	Max		
t _{PLH}	Propagation Delay	5.0	1.5	7.5	ns	
t _{PHL}	Propagation Delay	5.0	1.5	7.5	ns	

Note 4: Voltage Range 5.0 is 5.0V ±0.5V

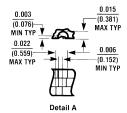
Capacitance

Symbol	Parameter	Max	Units	Conditions
C _{IN}	Input Capacitance	10.0	pF	V _{CC} = OPEN
C _{PD}	Power Dissipation	72.0	pF	$V_{CC} = 5.0V$
	Capacitance			

Physical Dimensions inches (millimeters) unless otherwise noted

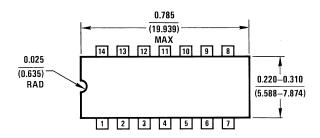


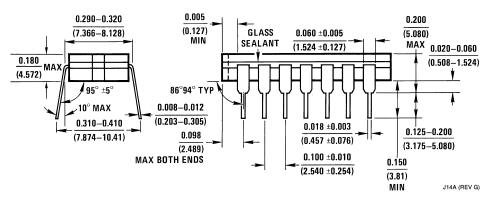
Bottom View



E20A (REV D)

20 Terminal Ceramic Leadless Chip Carrier (L) NS Package Number E20A

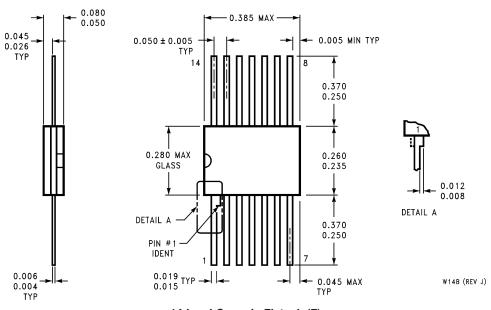




14-Lead Ceramic Dual-In-Line Package (D) **NS Package Number J14A**

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Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



14-Lead Ceramic Flatpak (F) **NS Package Number W14B**

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